

Description

The AP7346 is a dual high accuracy current limit, low dropout regulator with high output voltage accuracy, low $R_{DS(ON)}$, high PSRR, low output noise and low quiescent current. This regulator is based on a CMOS process.

Each of regulators includes a voltage reference, error amplifier, current limit circuit and an enable input to turn on/ off output. With the integrated resistor network, fixed output voltage versions can be delivered.

With its low power consumption and line and load transient response, the AP7346 is well suited for low power handheld communication equipment.

The AP7346 is packaged in X2-DFN1212-6 package and allows for smallest footprint and dense PCB layout.

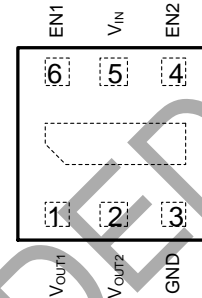
Features

- Low V_{IN} and Wide V_{IN} Range: 1.7V to 5.25V
- High Accuracy Current Limit: 157mA+/- 25mA
- V_{OUT} Accuracy: $\pm 1\%$
- Ripple Rejection: 75dB at 1kHz
- Low Output Noise: 60 μ Vrms from 10Hz to 100kHz
- Quiescent Current as Low as 35 μ A
- V_{OUT} Fixed 1.2V to 3.6V
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](#) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>**

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Assignments

Top View

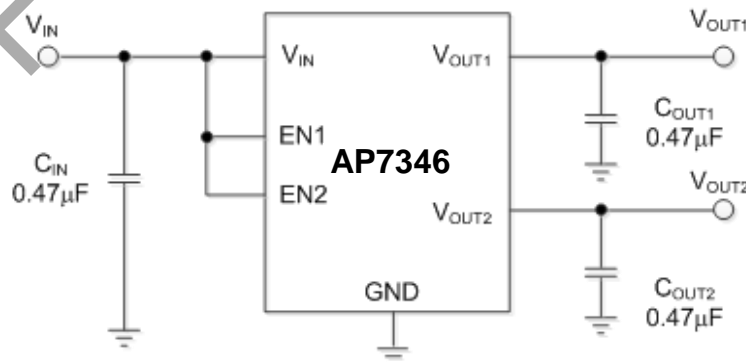


X2-DFN1212-6

Applications

- Fingerprint modulators
- Smart phones/PADS
- RF supplies
- Cameras
- Portable videos
- Portable media players
- Wireless adapters
- Wireless communications

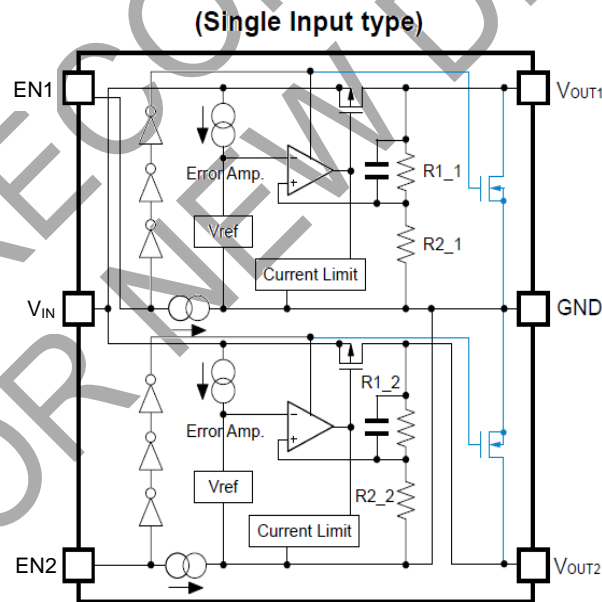
Typical Applications Circuit



Pin Descriptions

Pin Number	Pin Name	Function
1	V _{OUT1}	Channel 1 output voltage pin
2	V _{OUT2}	Channel 2 output voltage pin
3	GND	Ground
4	EN2	Channel 2 enable pin. This pin should be driven either high or low and must not be floating. Driving this pin high enables channel 2 output, while pulling it low puts Channel 2 regulator into shutdown mode.
5	V _{IN}	Power input pin
6	EN1	Channel 1 enable pin. This pin should be driven either high or low and must not be floating. Driving this pin high enables channel 1 output, while pulling it low puts Channel 1 regulator into shutdown mode.
-	Thermal PAD	In PCB layout, prefer to use large copper area to cover this pad for better thermal dissipation, then connect this area to GND or leave it open. However do not use it as GND electrode function alone.

Functional Block Diagram



With Discharge

Absolute Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified. Note 4)

Symbol	Parameter	Rating	Unit
V_{IN}	Input Voltage	6.0	V
V_{EN}	Input Voltage at EN Pins	6.0	V
V_{OUT}	Output Voltage	-0.3 to $V_{IN} + 0.3$	V
I_{OUT}	Output Current	130	mA
P_D	Power Dissipation	600	mW
T_A	Operating Ambient Temperature	-40 to +85	$^\circ\text{C}$
T_{STG}	Storage Temperature	-55 to +125	$^\circ\text{C}$

Note: 4. Stresses greater than those listed under *Absolute Maximum Ratings* can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these conditions is not implied. Exposure to *Absolute Maximum Ratings* for extended periods can affect device reliability.

Recommended Operating Conditions (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
V_{IN}	Input Voltage	1.7	5.25	V
I_{OUT}	Output Current	0	130	mA
T_A	Operating Ambient Temperature	-40	+85	$^\circ\text{C}$

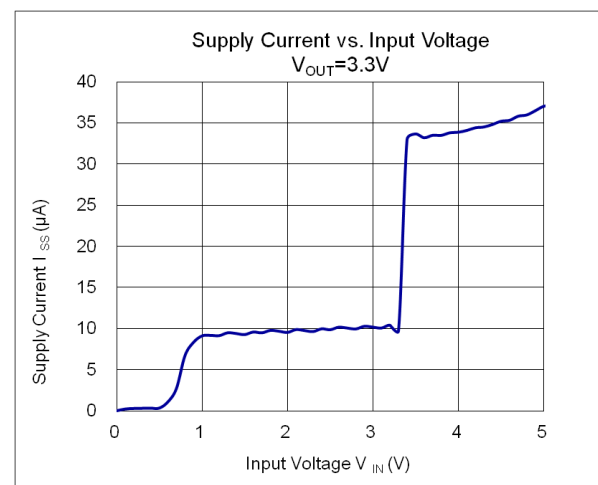
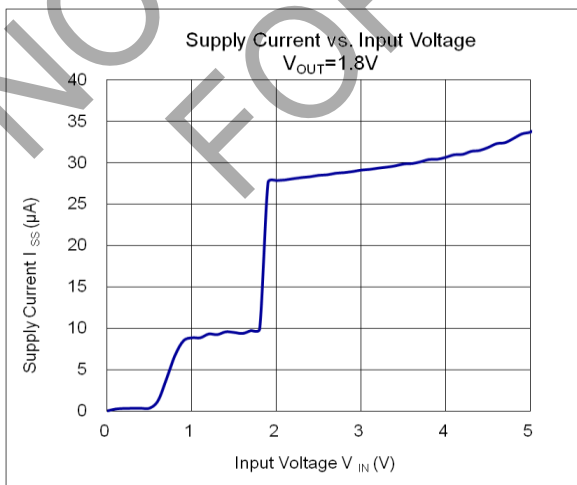
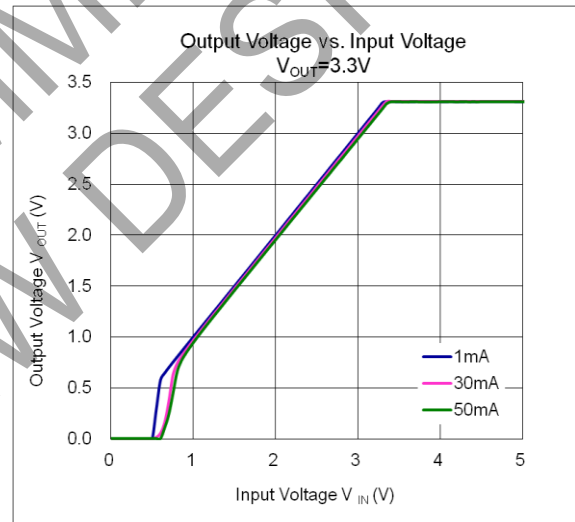
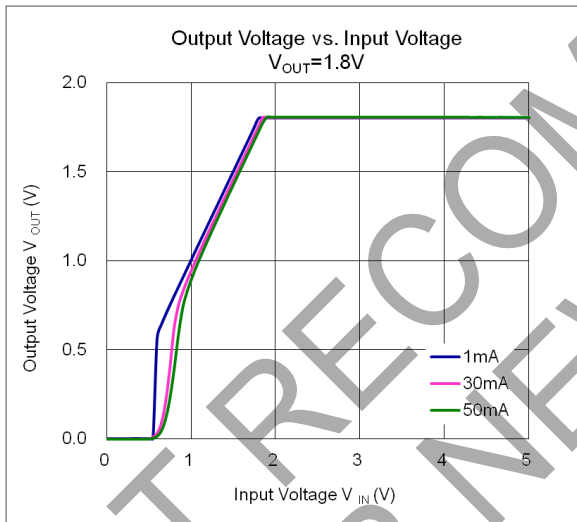
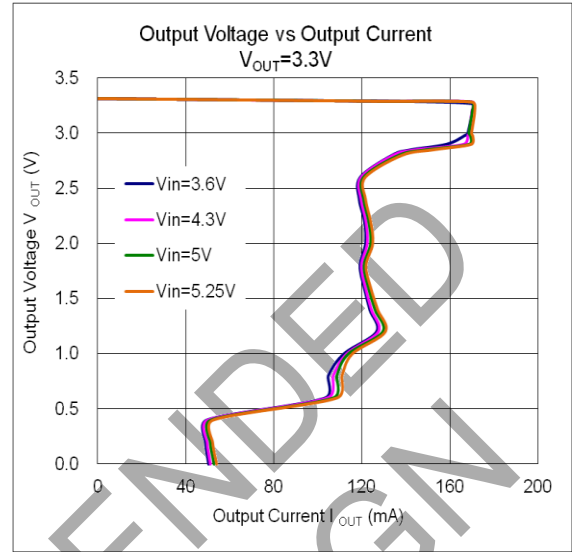
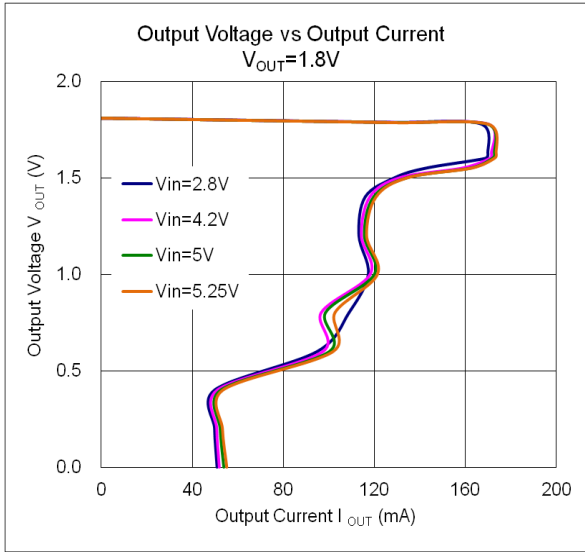
NOT RECOMMENDED FOR NEW DESIGN

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, $V_{IN} = V_{OUT}+1\text{V}$ ($V_{OUT} > 1.5\text{V}$), $V_{IN} = 2.5\text{V}$ ($V_{OUT} \leq 1.5\text{V}$), $I_{OUT} = 1\text{mA}$, $C_{IN} = C_{OUT} = 1.0\mu\text{F}$, unless otherwise specified.)

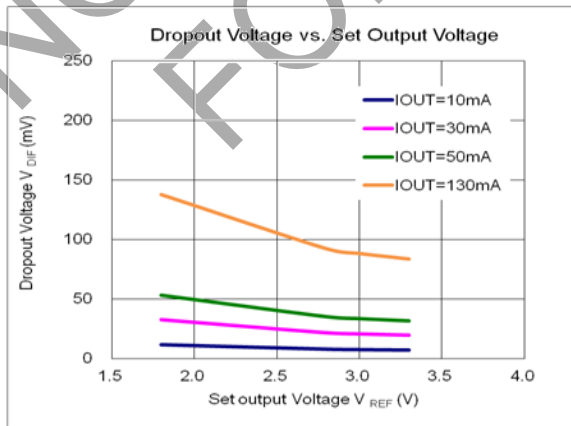
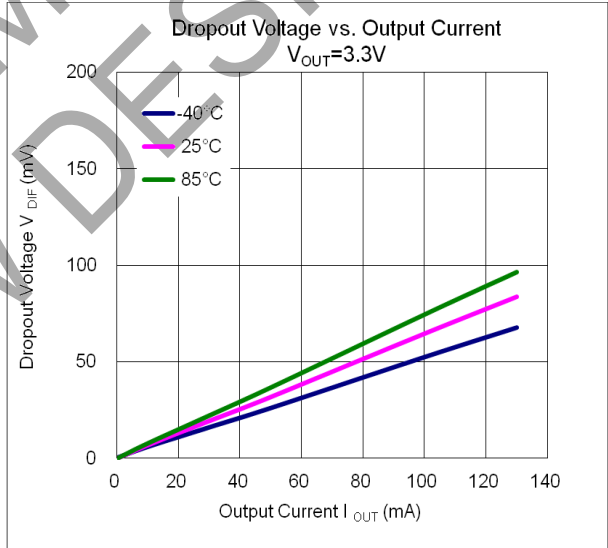
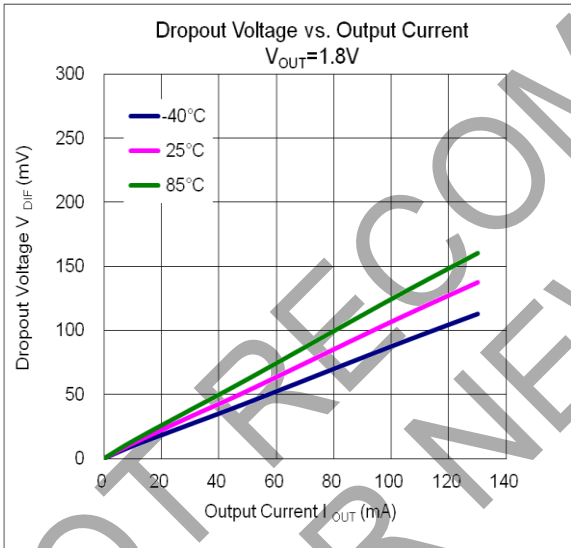
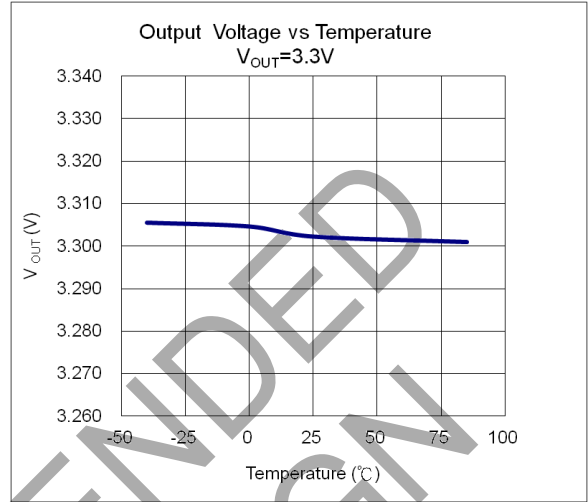
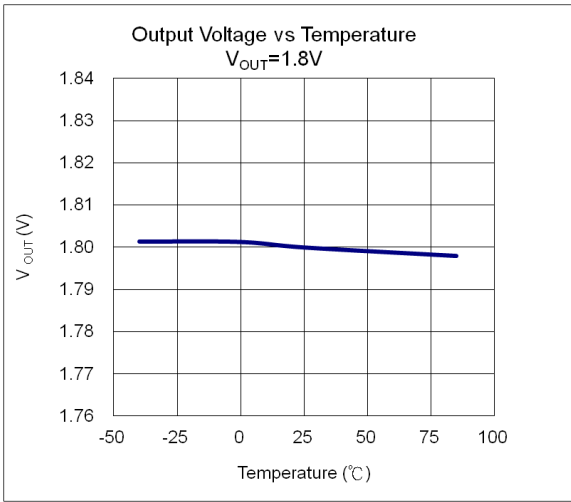
Parameter	Conditions	Min	Typ	Max	Unit	
Input Voltage	$T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$	1.7	–	5.25	V	
Output Voltage Accuracy (Note 11)	$V_{IN} = (V_{OUT-NOM}+1.0\text{V})$ to 5.25V , $I_{OUT} = 1\text{mA}$ to 120mA	$T_A = +25^\circ\text{C}$	-1	–	1	%
		$T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$	-1.5	–	1.5	
Line Regulation ($\Delta V_{OUT}/\Delta V_{IN}/V_{OUT}$)	$V_{IN} = (V_{OUT-NOM} + 1.0\text{V})$ to 5.25V , $I_{OUT} = 1.0\text{mA}$	–	0.02	0.1	%/V	
Load Regulation ($\Delta V_{OUT}/\Delta I_{OUT}$)	$V_{IN} = V_{OUT-NOM} + 1.0\text{V}$, $I_{OUT} = 1\text{mA}$ to 120mA	–	15	30	mV	
Quiescent Current (Note 6)	Set EN1 high, set EN2 low, or set EN2 high, set EN1 low, No load	–	35	50	μA	
	Set EN1/EN2 high, No load	–	70	100	μA	
$I_{STANDBY}$	Set EN1/EN2 low, No load	–	0.1	1.0	μA	
Output Current	–	130	–	–	mA	
Fold-back Short Current (Note 7)	V_{OUT} short to ground	–	55	–	mA	
PSRR (Note 8)	$V_{IN} = (V_{OUT}+1\text{V}) V_{DC} + 0.2\text{Vp-pAC}$, $V_{OUT} \geq 1.8\text{V}$, $I_{OUT} = 30\text{mA}$	–	75	–	dB	
Output Noise Voltage (Notes 8 & 9)	BW = 10Hz to 100kHz, $I_{OUT} = 30\text{mA}$	–	60	–	μVrms	
Dropout Voltage (Note 5)	$I_{OUT} = 120\text{mA}$	$V_{OUT} \leq 1.2\text{V}$	–	0.48	0.59	V
		$1.2\text{V} < V_{OUT} \leq 1.4\text{V}$	–	0.39	0.50	
		$1.4\text{V} < V_{OUT} \leq 1.7\text{V}$	–	0.35	0.44	
		$1.7\text{V} < V_{OUT} \leq 2.1\text{V}$	–	0.30	0.39	
		$2.1\text{V} < V_{OUT} \leq 2.5\text{V}$	–	0.26	0.34	
		$2.5\text{V} < V_{OUT} \leq 3.0\text{V}$	–	0.25	0.30	
		$3.0\text{V} < V_{OUT} \leq 3.6\text{V}$	–	0.22	0.29	
Output Voltage Temperature Coefficient	$I_{OUT} = 30\text{mA}$, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$	–	± 30	–	ppm/ $^\circ\text{C}$	
EN Input Low Voltage	–	0	–	0.5	V	
EN Input High Voltage	–	1.3	–	5.25	V	
EN Input Leakage	$V_{EN} = 0\text{V}$, $V_{IN} = 5.0\text{V}$ or $V_{EN} = 5.0\text{V}$, $V_{IN} = 0\text{V}$	-1.0	–	1.0	μA	
OCP	–	132	157	182	mA	
On Resistance of N-channel for Auto-discharge (Note 10)	$V_{IN} = 4.0\text{V}$, $V_{EN} = 0\text{V}$ (Disabled)	D Version Channels 1 & 2	–	50	–	Ω

- Notes:
- Dropout voltage is the voltage difference between the input and the output at which the output voltage drops 2% below its nominal value.
 - Quiescent current defined here is the difference in current between the input and the output.
 - Short circuit current is measured with V_{OUT} pulled to GND.
 - This specification is guaranteed by design.
 - To make sure lowest environment noise minimizes the influence on noise measurement.
 - AP7346 is available for built-in discharge.
 - Potential multiple grades based on following output voltage accuracy.

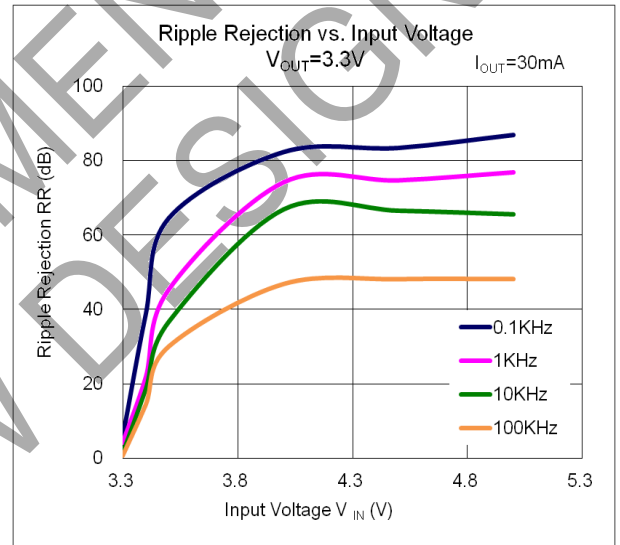
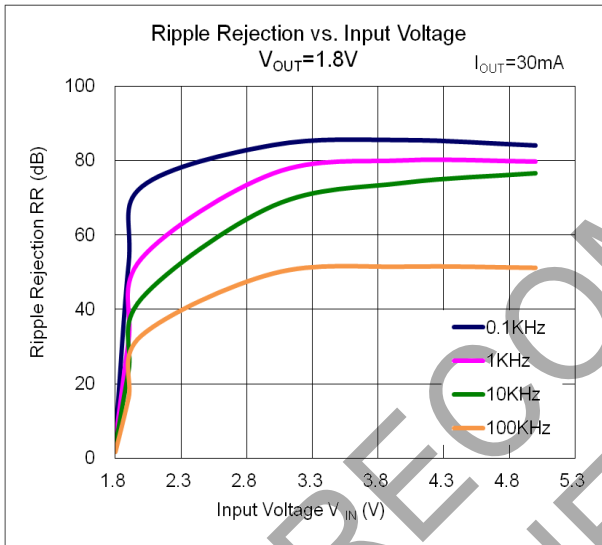
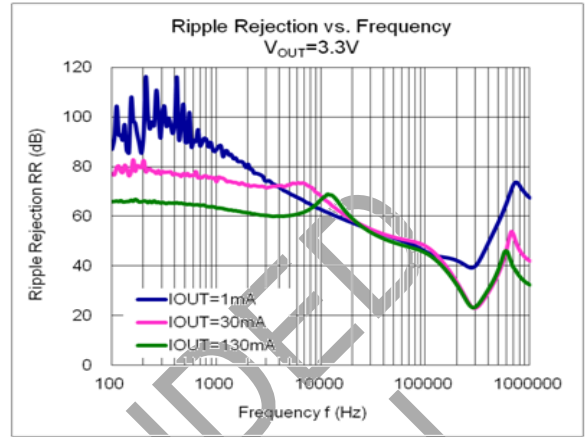
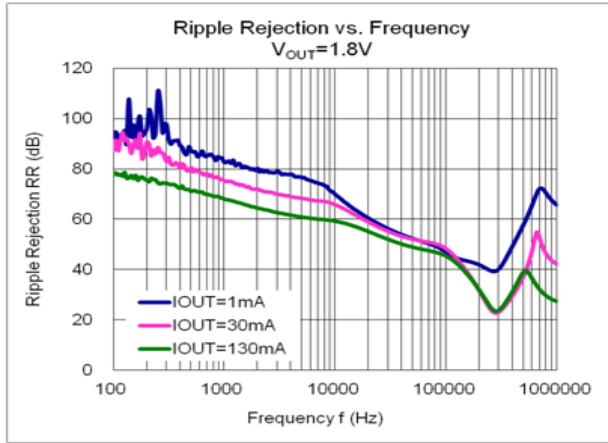
Performance Characteristics



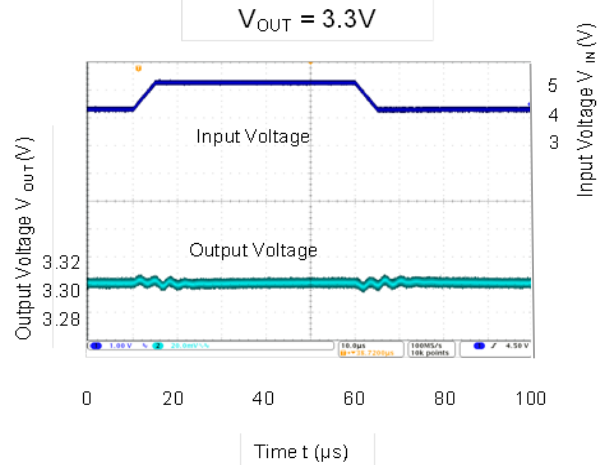
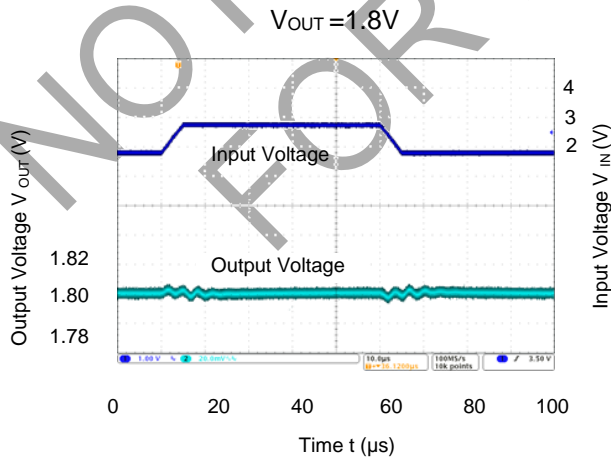
Performance Characteristics (continued)



Performance Characteristics (continued)

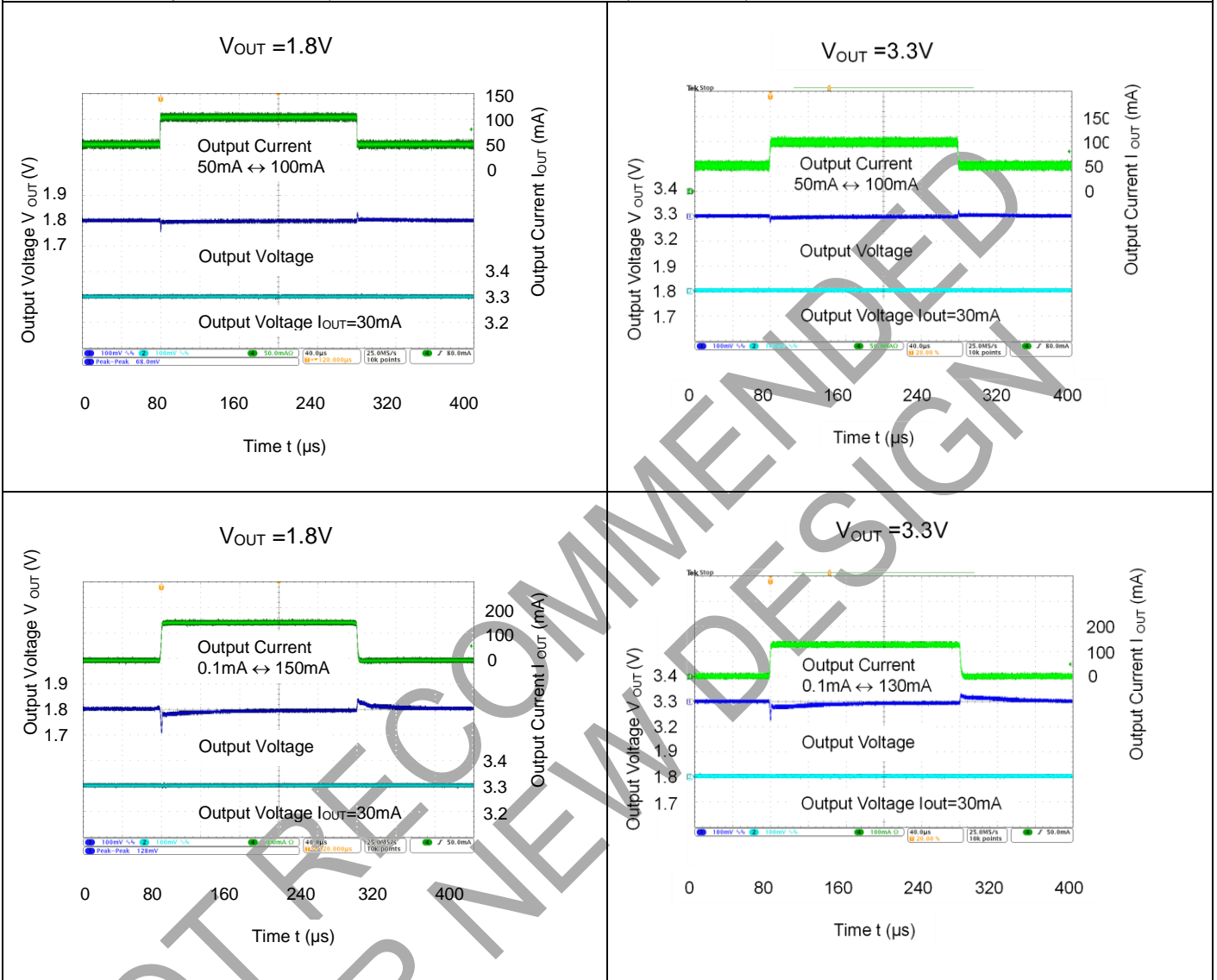


Line Transient Response Waveforms ($I_{OUT}=30mA$, $t_R=t_F=5\mu s$, $C_{IN}=none$, $C_{OUT1}=C_{OUT2}=0.47\mu F$, $T_A=+25^\circ C$)



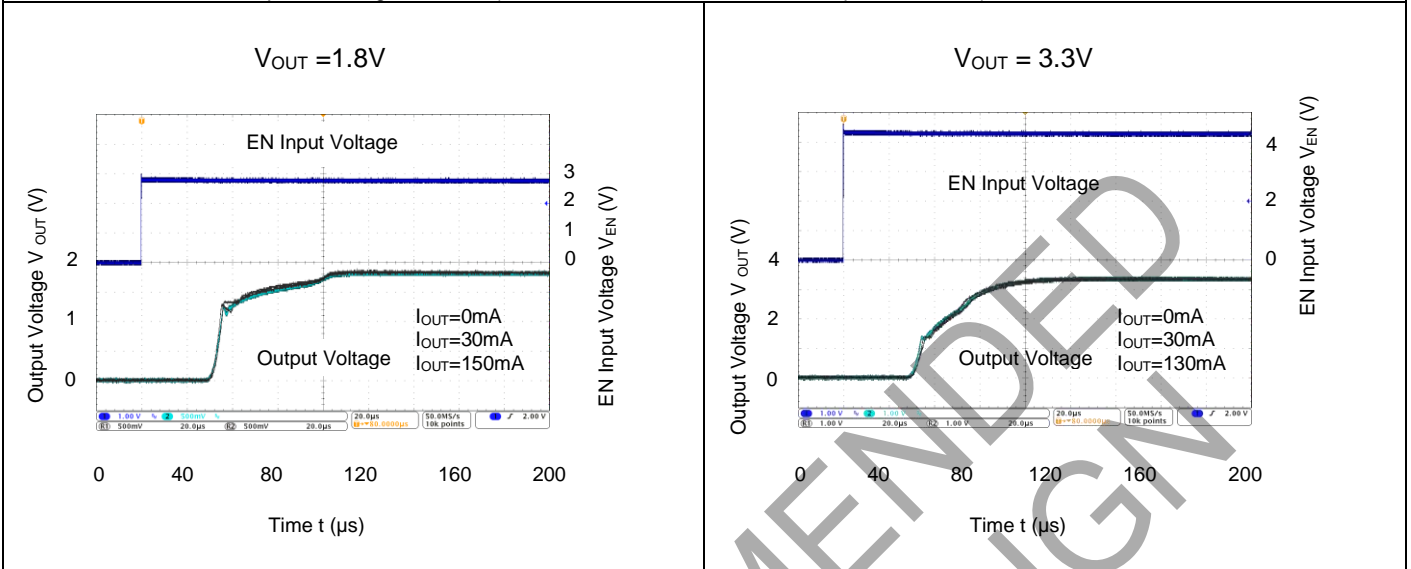
Performance Characteristics (continued)

Load Transient Response Waveforms ($V_{IN}=V_{OUT}+1V$, $C_{IN}=C_{OUT1}=C_{OUT2}=0.47\mu F$, $T_A=+25^\circ C$)

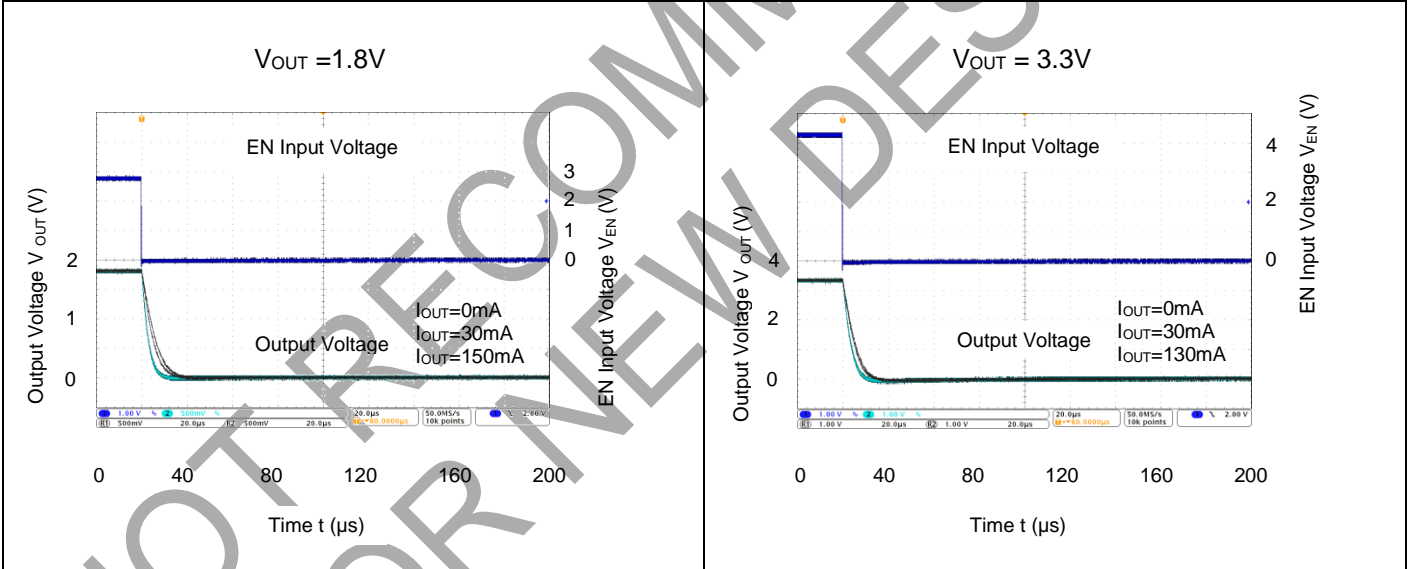


Performance Characteristics (continued)

Turn On Waveform of Output Discharge Versions ($V_{IN}=V_{OUT}+1V$, $C_{IN}=C_{OUT1}=C_{OUT2}=0.47\mu F$, $T_A=+25^\circ C$)



Turn Off Waveform of Output Discharge versions ($V_{IN}=V_{OUT}+1V$, $C_{IN}=C_{OUT1}=C_{OUT2}=0.47\mu F$, $T_A=+25^\circ C$)



Application Information

Output Capacitor

An output capacitor (C_{OUT}) is needed to improve transient response and maintain stability. The AP7346 is stable with very small ceramic output capacitors. The ESR (Equivalent Series Resistance) and capacitance drive the selection. If the application has large load variations, it is recommended to utilize low-ESR bulk capacitors. It is recommended to place ceramic capacitors as close as possible to the load and the GND pin and care should be taken to reduce the impedance in the layout.

Input Capacitor

To prevent the input voltage from dropping during load steps, it is recommended to utilize an input capacitor (C_{IN}). A minimum $0.47\mu\text{F}$ ceramic capacitor is recommended between V_{IN} and GND pin to decouple input power supply glitch. This input capacitor must be located as close as possible to the device to assure input stability and reduce noise. For PCB layout, a wide copper trace is required for both V_{IN} and GND pin.

Enable Control

The AP7346 is turned on by setting the EN pins high, and is turned off by pulling it low. If this feature is not used, the EN pins should be tied to V_{IN} pin to keep the regulator output on at all time. To ensure proper operation, the signal source used to drive the EN pins must be able to swing above and below the specified turn-on/off voltage thresholds listed in the *Electrical Characteristics* section.

Short-Circuit Protection

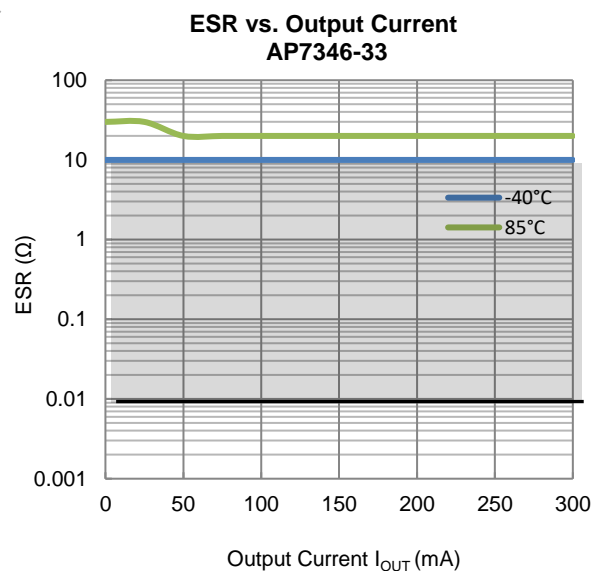
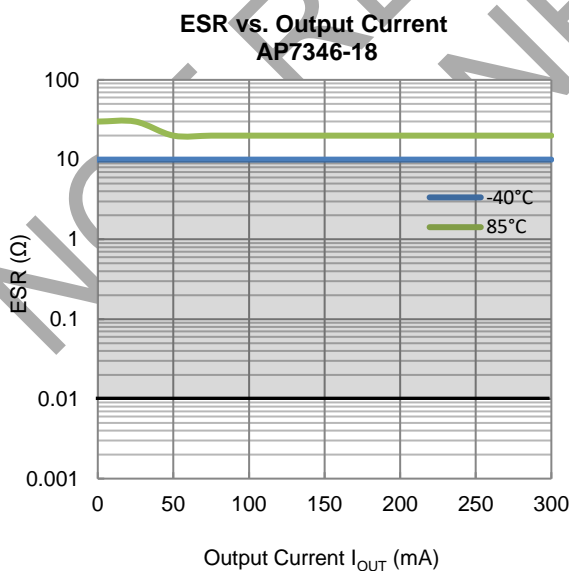
When V_{OUT} pins are short-circuit to GND, short-circuit protection will be triggered and clamp the output current to approximately 60mA. This feature protects the regulator from overcurrent and damage due to overheating.

Layout Considerations

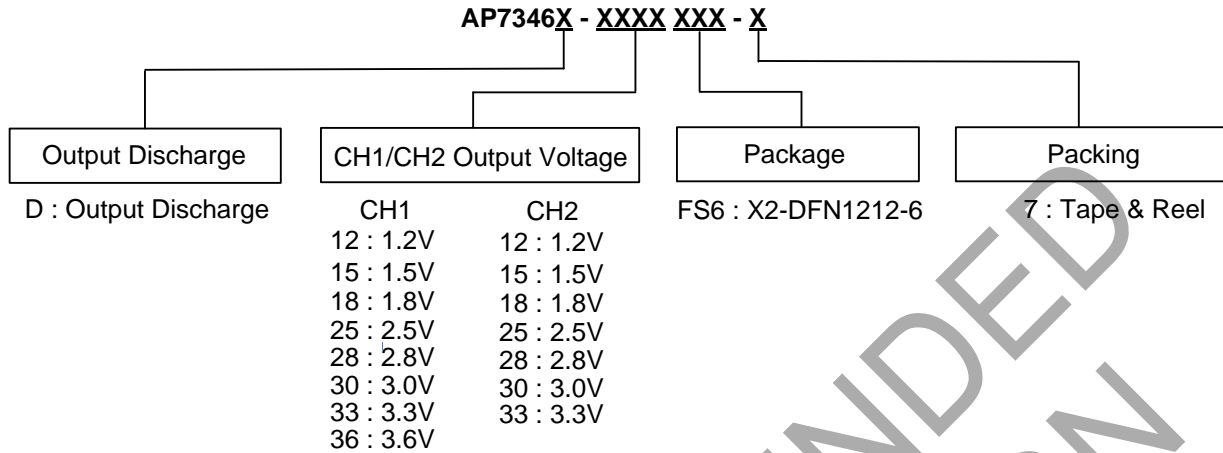
For good ground loop and stability, the input and output capacitors should be located close to the input, output, and GND pin of the device. The regulator GND pin should be connected to the external circuit ground to reduce voltage drop caused by trace impedance. Ground plane is generally used to reduce trace impedance. Wide trace should be used for large current paths from V_{IN} to V_{OUT} , and load circuit.

ESR vs. Output Current

Ceramic type output capacitor is recommended for this series; however, the other output capacitors with low ESR also can be used. The relations between I_{OUT} (Output Current) and ESR of an output capacitor are shown below. The stable region is marked as the hatched area in the graph. Measurement conditions: Frequency Band: 10Hz to 2MHz, Temperature: -40°C to $+85^{\circ}\text{C}$.



Ordering Information

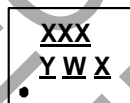


Part Number	Part Number Suffix	Package Code	Package	Packing	
				Qty.	Carrier
AP7346D-XXXXFS6-7	-7	FS6	X2-DFN1212-6	5000	7" Tape & Reel

Marking Information

(1) X2-DFN1212-6

(Top View)



XXX : Identification Code
Y : Year : 0~9
W : Week : A~Z : 1~26 week;
 a~z : 27~52 week; z represents
 52 and 53 week
X : Internal code

Part Number	V _{OUT1} /V _{OUT2}	Package	Identification Code
AP7346D-1218FS6-7	1.2V/1.8V	X2-DFN1212-6	EAA
AP7346D-1528FS6-7	1.5V/2.8V	X2-DFN1212-6	EAB
AP7346D-1815FS6-7	1.8V/1.5V	X2-DFN1212-6	EAC
AP7346D-1818FS6-7	1.8V/1.8V	X2-DFN1212-6	EAD
AP7346D-1828FS6-7	1.8V/2.8V	X2-DFN1212-6	EAE
AP7346D-1833FS6-7	1.8V/3.3V	X2-DFN1212-6	EAF
AP7346D-2518FS6-7	2.5V/1.8V	X2-DFN1212-6	EAG

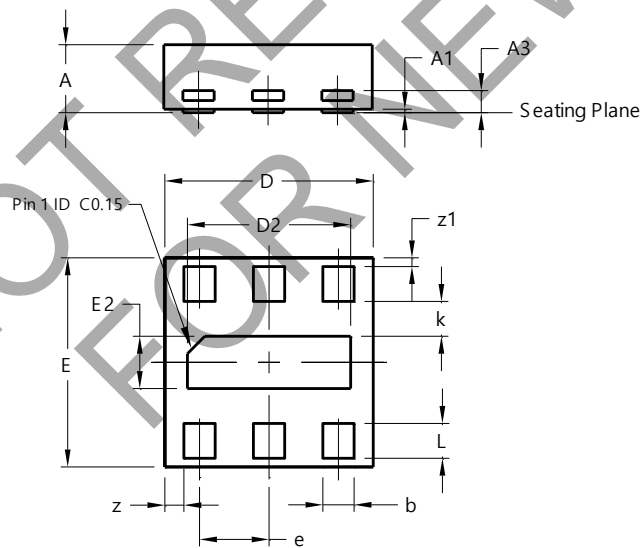
Marking Information (continued)

Part Number	V _{OUT1} /V _{OUT2}	Package	Identification Code
AP7346D-2812FS6-7	2.8V/1.2V	X2-DFN1212-6	EAH
AP7346D-2818FS6-7	2.8V/1.8V	X2-DFN1212-6	EAJ
AP7346D-2825FS6-7	2.8V/2.5V	X2-DFN1212-6	EAK
AP7346D-2833FS6-7	2.8V/3.3V	X2-DFN1212-6	EAM
AP7346D-3018FS6-7	3.0V/1.8V	X2-DFN1212-6	EAN
AP7346D-3028FS6-7	3.0V/2.8V	X2-DFN1212-6	EAP
AP7346D-3030FS6-7	3.0V/3.0V	X2-DFN1212-6	EAR
AP7346D-3318FS6-7	3.3V/1.8V	X2-DFN1212-6	EAS
AP7346D-3328FS6-7	3.3V/2.8V	X2-DFN1212-6	EAT
AP7346D-3330FS6-7	3.3V/3.0V	X2-DFN1212-6	EAU
AP7346D-3333FS6-7	3.3V/3.3V	X2-DFN1212-6	EAV
AP7346D-3612FS6-7	3.6V/1.2V	X2-DFN1212-6	EAW

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

X2-DFN1212-6

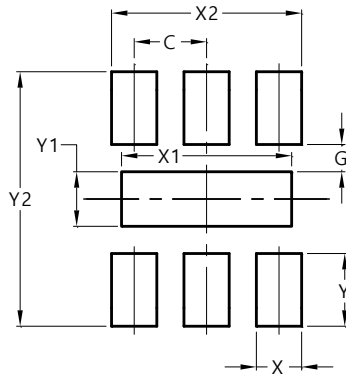


X2-DFN1212-6			
Dim	Min	Max	Typ
A	-	0.40	0.39
A1	0.00	0.05	0.020
A3	-	-	0.13
b	0.13	0.23	0.18
D	1.15	1.25	1.20
D2	0.89	0.99	0.94
E	1.15	1.25	1.20
E2	0.25	0.35	0.30
e	-	-	0.40
k	0.15	0.25	0.20
L	0.15	0.25	0.20
z	-	-	0.11
z1	-	-	0.05
All Dimensions in mm			

Suggested Pad Layout

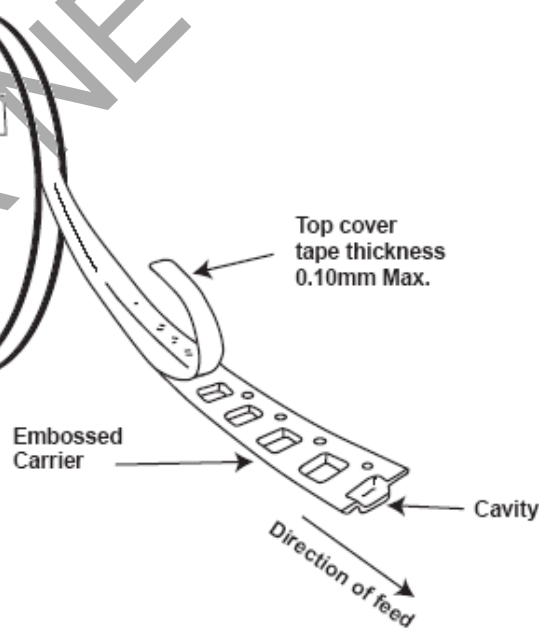
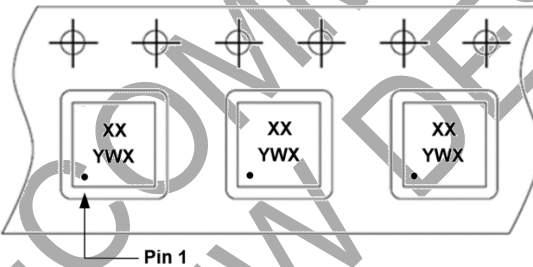
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

X2-DFN1212-6



Dimensions	Value (in mm)
C	0.400
G	0.150
X	0.250
X1	0.940
X2	1.050
Y	0.400
Y1	0.300
Y2	1.400

Tape Orientation



Note: The taping orientation of the other package type can be found on our website at <https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf>.

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